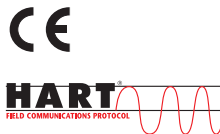


MST 8 Series

Temperature field transmitter

HART® MST885

Temperature EN



Application

- Temperature field transmitter with HART® - protocol for converting various input signals to an analogue, scalable 4 to 20 mA signal.
- Input:
 - Resistance thermometer (RTD)
 - Thermocouples (TC)
 - Resistance transmitter (Ω)
 - Voltage transmitter (mV)
- HART®-protocol for operating the device on site using handheld terminal or remotely via the PC.

Your benefits

- Universal Input (RTD/TC/mV/ Ω)
- Universal setting with HART®-protocol
- Operation, visualisation and maintenance via PC, e. g. configurationsoftware "HHTemp_V2.06E"
- 2 wire technology, 4...20mA analog output
- Galvanic isolation (2000V AC)
- High accuracy in total ambient temperature range:
 - 0.02% of span for Pt100 sensor
 - 0.1% of span for TC sensor
- Fault signal on sensor break or short circuit, presettable to NAMUR NE 43
- Internal temperature sensor for active temperature compensation (for TC sensor)
- Backlight LCD-Display, rotatable in 270°-stages

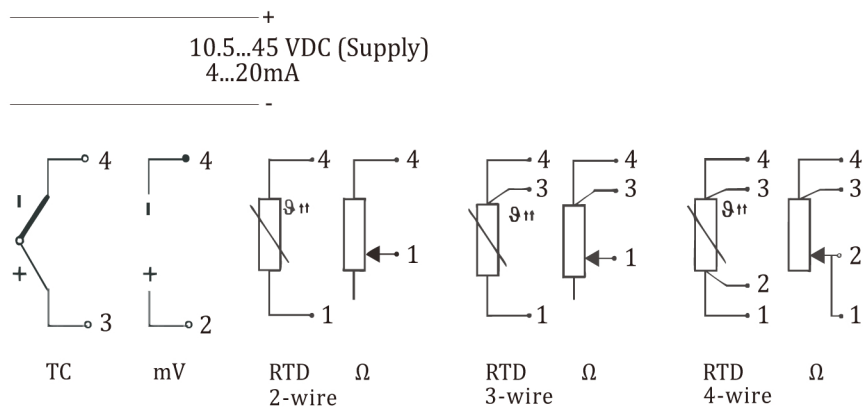
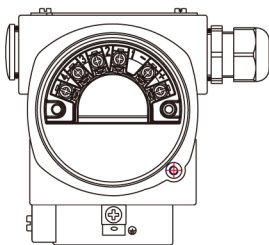
Technical data

Input			
Input	Type	Measurement ranges	Min. meas. ranges
Resistances thermometer (RTD)	Pt100	-200 to 850 °C (-328 to 1562 °F)	10°C
	Pt500	-200 to 250 °C (-328 to 482 °F)	10°C
	Pt1000	-200 to 250 °C (-328 to 482 °F)	10°C
	<i>acc. to IEC 60751 (a = 0.00385)</i>		
	Cu50	-50 to 150 °C (-58 to 302 °F)	10°C
	Cu100	-50 to 150 °C (-58 to 302 °F)	10°C
Resistancetransmitter	Ni100	-60 to 180 °C (-76 to 356°F)	10°C
	Ni500	-60 to 180 °C (-76 to 356°F)	10°C
	Ni1000	-60 to 150 °C (-76 to 302 °F)	10°C
	<i>acc. to DIN 43760 (a = 0.006180)</i>		
Resistancetransmitter	Widerstand Ω	0 to 400 Ω	10 Ω
		0 to 2000 Ω	10 Ω
Connection type: 2-, 3- or 4-wire connection, Sensor current: < 0.5 mA			

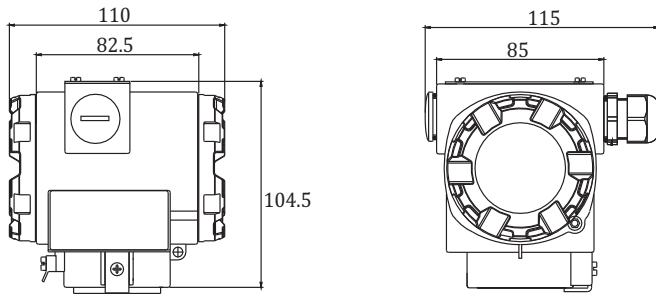
Input				
Thermocouples(TC)	B (PtRh30-PtRh6)	0 to +1820 °C (32 to 3308 °F)	500°C	
	E (NiCr-CuNi)	-270 to +1000 °C (-454 to 1832 °F)	50°C	
	J (Fe-CuNi)	-210 to +1200 °C (-346 to 2192 °F)	50°C	
	K (NiCr-Ni)	-270 to +1372 °C (-454 to 2501 °F)	50°C	
	N (NiCrSi-NiSi)	-270 to +1300 °C (-454 to 2372 °F)	50°C	
	R (PtRh13-Pt)	-50 to +1768 °C (-58 to 3214 °F)	500°C	
	S (PtRh10-Pt)	-50 to +1768 °C (-58 to 3214 °F)	500°C	
	T (Cu-CuNi)	-270 to +400 °C (-454 to 752 °F)	50°C	
Voltage transmitters(mV)	(mV)	-10 to 75mV	5mV	
		-100 to 100mV	5mV	
		-500 to 500mV	10mV	
		-1000 to 1000mV	20mV	
Connection type: 2-wire connection, Sensor current: < 0.5 mA				
Power supply				
Supply voltage		7.5 to 45V DC		
Output				
Output signal		4 ... 20 mA		
Load		$R_{max} = [(U_{supply} - 7,5) / 0,022] \Omega$		
Signal on alarm		Underranging: Linear drop to 3.8 mA		
		Overranging: linear rise to 20.5 mA		
		Sensor break; sensor open-circuit: 3.6 mA or 22.0 mA		
Linearisation/transmission behaviour		Temperature linear, resistance linear, voltage linear		
Galvanic isolation		U=2000V AC (input/output)		
Performance characteristics				
Response time		0.25 s		
Reference conditions		Calibration temperature: +23 °C (73.4K) ± 5 K		
Accuracy	Input	Type	Accuracy	
		RTD	Pt100. Ni100	0.02%
			Pt500. Ni500	0.05%
			Pt1000. Ni1000	0.3%
			Cu50	0.2%
	Cu100		0.3%	
	TC	K, J, T, E	typ. 0.1%	
		N	typ. 0.1%	
		S, B, R	typ. 0.1%	
	Ω	10 to 400 Ω	± 0.1 Ω or 0.02%	
10 to 2000 Ω		± 1.5 Ω or 0.03%		
mV	-10 to 75mV	± 4 µV or 0.02%		
	-100 to 100mV	± 4 µV or 0.02%		
	-100 to 500mV	± 7.5 µV or 0.02%		
	-100 to 2000mV	± 7.5 µV or 0.02%		
Switch on delay		≤ 2 s		
Influence of supply voltage		≤ ± 0.01%/V deviation from 24V		
Influence of ambient temperature (Total temperature drift)		Input temperature drift + Output temperature drift Input 0 to 2000 Ω, typ. 0,0015% of measured value Output 4 to 20mA, typ. 0,005% of measured value		
Influence of load		± 0,02%/100Ω, Values refer to the full scale value		
Influence of cold junction (for TC)		Pt100 DIN IEC 60751 Cl. B		
Long-term stability		≤ 0,1 K/year oder ≤ 0,05%/year The % refer to the set span.		
Self stability configuration		0 to 2%		
Filter configurating		0 to 160µA		
Resolution		0,3µA		

Environment conditions	
Installation instructions	Installation angle: no limit
	Installation area: field. Connection for sensor: M20 internal thread
Storage temperature	
Ambient temperature limits	-40 to +85 °C (-40 to 185 °F)
Storage temperature	-40 to +100 °C (-40 to 212 °F)
Condensation	Allowable
Degree of protection	IP 66
Shock and vibration resistance	4g / 2 to 150Hz as per IEC 60068-26
Electromagnetic compatibility (EMC)	Interference immunity and interference emission according to IEC 61326-1 : 2006
Others	
Dimensions	128 x 89.4 x 77 mm
Weight	Approx. 900 g
Materials	Die-cast aluminium
Display	LCD-Display, with backlight, visible range 32.5 x 22.5mm Main display: 5-digit, 7-segment, digit height 8mm, range: -19999...99999 Additional display: 8-digit 14 segment , digit height 5mm for sensor type and units
Certificate and approvals	
CE-Mark	The device meets the legal requirements of the CE directives. Muesen Technik confirms that the devices has been successfully tested by applying the CE mark.
Other standards and guidelines	IEC 60529: Degree of protection provided by housing (IP-Code) IEC 61010: Safety requirements for electrical measurement, control and laboratory use. IEC 61326: Electromagnetic compatibility (EMC requirements) NAMUR: Standard working group for measurement and control technology in the chemical industry.

Electrical Connection

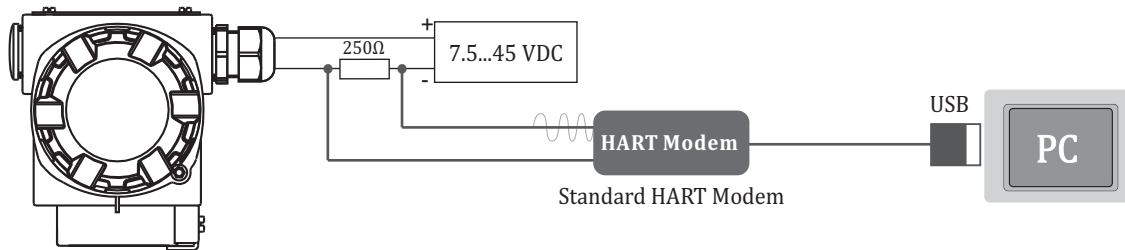


Dimensions



Dimensions in mm

Programming



Ordering code

MST 8 Series

Type	HART® Programmable Temperature field transmitter galvanic isolated, with HART® -Protocol	MST885		
Input (configurable)	Factory preset (Pt100, 3-wire, 0...100 °C)		1 0 0	
	Configuration according to customer specification		9 9 9	
Output	4...20mA, 2-wire			0 0
Additives	None			0 0
	According to customer specification			9 9

Inventory

Type	Interface
MST885-100-00-00	HART®

